

Application Data Sheet**Applicant Information**

Applicant Authority type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Hideharu
Family Name:: ITATANI
City of Residence:: Tokyo
Country of Residence:: JAPAN

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Sadayoshi
Family Name:: HORII
City of Residence:: Tokyo
Country of Residence:: JAPAN

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Masayuki
Family Name:: ASAI
City of Residence:: Tokyo
Country of Residence:: JAPAN

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Atsushi
Family Name:: SANO
City of Residence:: Tokyo
Country of Residence:: JAPAN

Correspondence Information

Correspondence Customer Number:: 25944

Application Information

Application Type:: National Phase
Subject Matter:: Utility
CD-ROM or CD-R:: None
Title:: METHOD OF MANUFACTURING
SEMICONDUCTOR DEVICE AND
SUBSTRATE PROCESSING APPARATUS
Attorney Docket Number:: 122430
Total Drawing Sheets:: 6
Small Entity:: No

Representative Information

Domestic Priority Information			
Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This Application is a	National Stage of	PCT/JP03/08964	07/15/03
Foreign Priority Information			
Country::	Application Number::	Filing Date::	Priority Claimed::
JAPAN	2002-205627	07/15/02	Yes
Assignee Information			
Assignee Name::		HITACHI KOKUSAI ELECTRIC INC.	
Street of mailing address::		14-20, 3-chome, Higashi-Nakano,	
		Nakano-ku	
City of mailing address::		Tokyo	
Country of mailing address::		JAPAN	
Postal or Zip Code of mailing address::		164-8511	